

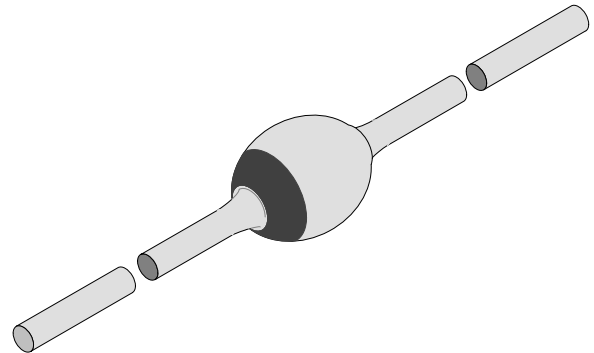
Silicon Mesa Rectifiers

Features

- Glass passivated junction
- Hermetically sealed package

Applications

High voltage fast rectifier



94 9539

Absolute Maximum Ratings

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Value	Unit
Peak reverse voltage, non repetitive		BY268	V_{RSM}	1600	V
Peak reverse voltage, non repetitive		BY269	V_{RSM}	1800	V
Reverse voltage		BY268	V_R	1400	V
Reverse voltage		BY269	V_R	1600	V
Peak forward surge current	$t_p=10\text{ms}$		I_{FSM}	20	A
Average rectifier output current			I_{FAV}	0.8	A
Junction temperature			T_j	175	$^\circ\text{C}$
Storage temperature range			T_{stg}	-65...+175	$^\circ\text{C}$

Maximum Thermal Resistance

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	on PC board with spacing 25 mm	R_{thJA}	110	K/W

Characteristics

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F=0.4\text{A}$		V_F			1.25	V
Reverse current	$V_R=1400\text{V}$	BY268	I_R		1	2	μA
	$V_R=1600\text{V}$	BY269	I_R		1	2	μA
	$V_R=1400\text{V}, T_j=100^\circ\text{C}$	BY268	I_R			15	μA
	$V_R=1600\text{V}, T_j=100^\circ\text{C}$	BY269	I_R			15	μA
Reverse recovery time	$I_F=0.5\text{A}, I_R=1\text{A}, I_T=250\text{mA}$		t_{rr}			400	ns

Typical Characteristics ($T_j = 25^\circ\text{C}$ unless otherwise specified)

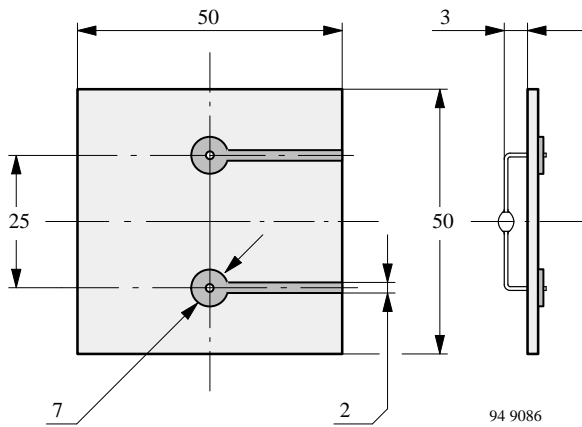


Figure 1 : Epoxy glass hard tissue, board thickness 1.5 mm,
 $R_{thJA} \leq 110 \text{ K/W}$

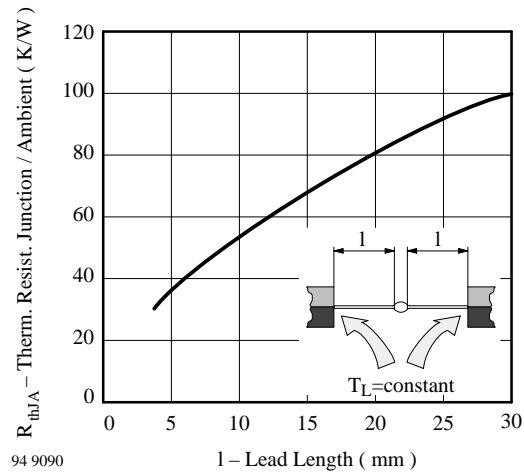


Figure 2 : Thermal Resistance vs. Lead Length

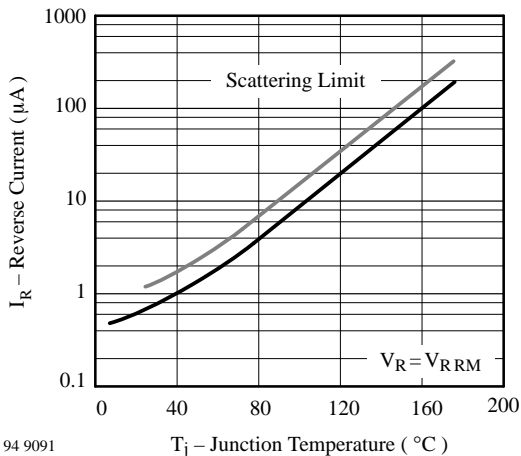


Figure 3 : Reverse Current vs. Junction Temperature

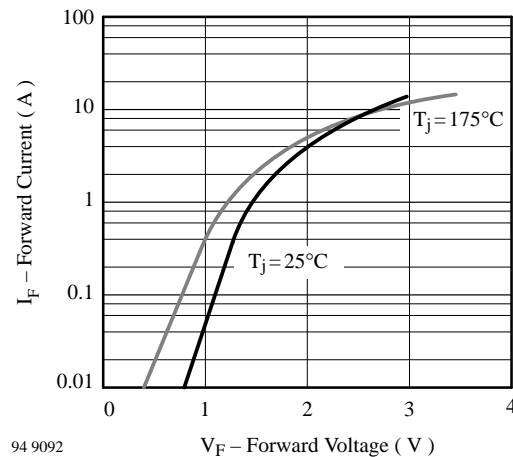


Figure 4 : Forward Current vs. Forward Voltage

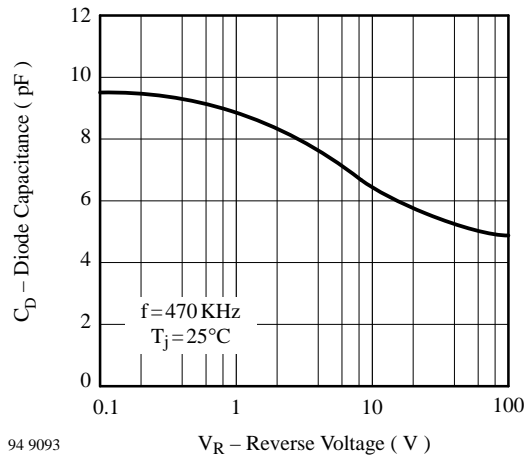
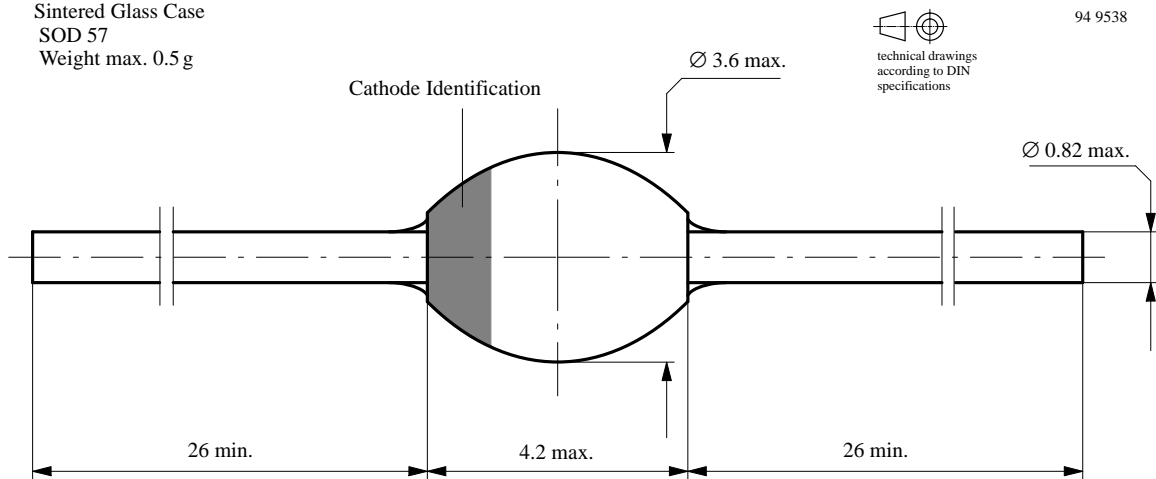


Figure 5 : Diode Capacitance vs. Reverse Voltage

Dimensions in mm

Sintered Glass Case
SOD 57
Weight max. 0.5 g



OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements and
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

Of particular concern is the control or elimination of releases into the atmosphere of those substances which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) will soon severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of any ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA and
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with and do not contain ozone depleting substances.

We reserve the right to make changes to improve technical design without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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